CVD of Laminar Ceramic Composites

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Laminar ceramic composites can easily be produced during chemical vapor deposition (CVD) by changing the composition of the reactant gas mixture. Several morphologies can be developed depending on whether the composition is changed instantaneously or gradually. The system TiN/TiB2 has been selected for detailed study. TiB2 can be utilized in advanced technologies, but in order to prevent extensive boronation of the substrate during deposition a diffusion barrier is required. TiN is shown to be a good diffusion barrier. Results will be presented of the deposition of TiB2 on a TiN substrate mimicking the instantaneous change in composition of the gas mixture. Furthermore the codeposition of TiB2 and TiN will be presented.